

FAST CMOS OCTAL BUS TRANSCEIVER (OPEN DRAIN)

IDT74FCT621T/AT

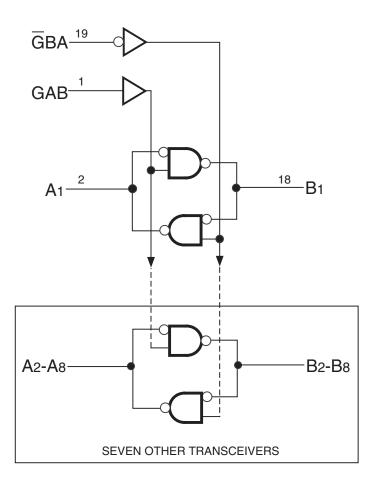
FEATURES:

- Std. and A grades
- Low input and output leakage ≤1µA (max.)
- CMOS power levels
- True TTL input and output compatibility:
 - -VOH = 3.3V(typ.)
 - -VOL = 0.3V(typ.)
- Meets or exceeds JEDEC standard 18 specifications
- · Power off disable outputs permit "live insertion"
- Available in SOIC package

DESCRIPTION:

The IDT74FCT621T is an octal transceiver with non-inverting Open-Drain bus compatible outputs in both send and receive directions. The B bus outputs are capable of sinking 64mA providing very good capacitive drive characteristics. These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timing.

FUNCTIONAL BLOCK DIAGRAM

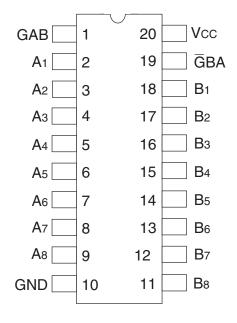


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NOVEMBER 2016

INDUSTRIAL TEMPERATURE RANGE

PINCONFIGURATION



SOIC TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Symbol Description		Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	–0.5 to +7	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	–65 to +150	°C
Ιουτ	DC Output Current	-60 to +120	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed Vcc by +0.5V unless otherwise noted.

2. Inputs and Vcc terminals only.

3. Output and I/O terminals only.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	6	10	pF
Соит	Output Capacitance	Vout = 0V	8	12	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PINDESCRIPTION

Pin Names	Description
GBA, GAB	EnableInputs
A1 – A8	A Inputs or Open-drain Outputs
B1 – B8	B Inputs or Open-drain Outputs

FUNCTION TABLE⁽¹⁾

Ena	bleInputs	
GBA GAB		Function
L	L	B data to A bus
Н	Н	A data to B bus
H L		OFF
L H		B data to A bus
		A data to B bus

NOTE:

1. H = HIGH Voltage Level.

L = LOW Voltage Level.

OFF = HIGH if pull-up resistor is connected to Open-Drain output.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

 $\label{eq:conditions} Following \ Conditions \ Apply \ Unless \ Otherwise \ Specified:$

Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = $5.0V \pm 5\%$

Symbol	Parameter	Test Condi	Test Conditions ⁽¹⁾		Тур. ⁽²⁾	Max.	Unit
VIH	Input HIGH Level	Guaranteed Logic HIGH Level	Guaranteed Logic HIGH Level		_	_	V
VIL	Input LOW Level	Guaranteed Logic LOW Level	GuaranteedLogicLOWLevel		_	0.8	V
Ін	Input HIGH Current ⁽⁴⁾	Vcc = Max., VI = 2.7V		—	_	±1	μA
lil	Input LOW Current ⁽⁴⁾	Vcc = Max., VI = 0.5V		_	_	±1	μA
li	Input HIGH Current ⁽⁴⁾	Vcc = Max., VI = Vcc (Max.)		—	_	±1	μA
Vik	Clamp Diode Voltage	Vcc = Min., IN= -18mA	Vcc = Min., IN= -18mA		-0.7	-1.2	V
Юн	Output HIGH Current	Vcc = Max. VIN = VIH or VIL	VOH = Vcc (Max.)	-	-	20	μA
Vol	Output LOW Voltage (B Bus)	Vcc = Min. VIN = VIH or VIL	IOL = 64mA ⁽³⁾	-	0.3	0.55	V
Vol	Output LOW Voltage (A Bus)	VCC = Min. VIN = VIH or VIL	IOL = 48mA ⁽³⁾	-	0.3	0.5	V
IOFF	Input/Output Power Off Leakage ⁽⁴⁾	VCC = 0V, VIN or Vo - 4.5V	Vcc = 0V, Vin or Vo - 4.5V		-	±1	μA
Vн	Input Hysteresis	_	_		200	_	mV
Icc	Quiescent Power Supply Current	Vcc = max., VIN = GND or Vcc		—	0.01	1	mA

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, $+25^{\circ}C$ ambient.

3. These are maximum IoL values per output, for 8 outputs turned on simultaneously. Total maximum IoL (all outputs) is 512mA for commercial and 384mA for military. Derate IoL for number of outputs exceeding 8 turned on simultaneously.

4. The test limit for this parameter is $\pm 5\mu A$ at TA = $-55^{\circ}C$.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Test Conditions ⁽¹⁾		Тур.(2)	Max.	Unit
Δlcc	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = Max.$ $V_{IN} = 3.4V^{(3)}$		—	0.5	2	mA
ICCD	Dynamic Power Supply Current ⁽⁴⁾	Vcc = Max. Outputs Open GBA = GAB = GND or Vcc One Input Toggling 50% Duty Cycle	VIN = VCC VIN = GND	_	0.15	0.25	mA/MHz
lc	Total Power Supply Current ^(6,7)	Vcc = Max. Outputs Open GBA = GAB = GND or Vcc One Bit Toggling at fi =10MHz	VIN = VCC $VIN = GND$ $VIN = 3.4V$ $VIN = GND$	_	1.5 1.8	3.5 4.5	mA
		50% Duty Cycle					
		Vcc = Max. OutputsOpen GBA = GAB = GND or Vcc	VIN = VCC VIN = GND	_	3	6 ⁽⁵⁾	
		Eight Bits Toggling at fi = 2.5MHz 50% Duty Cycle	VIN = 3.4V VIN = GND	_	5	14 ⁽⁵⁾	

NOTES:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Per TTL driven input (VIN = 3.4V); all other inputs at Vcc or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

5. Values for these conditions are examples of the Icc formula. These limits are guaranteed but not tested.

6. IC = IQUIESCENT + INPUTS + IDYNAMIC

IC = ICC + Δ ICC DHNT + ICCD (fCP/2 + fiNi)

Icc = Quiescent Current

 Δ Icc = Power Supply Current for a TTL High Input (VIN = 3.4V)

DH = Duty Cycle for TTL Inputs High

NT = Number of TTL Inputs at DH

Icco = Dynamic Current Caused by an Output Transition Pair (HLH or LHL)

fcp = Clock Frequency for Register Devices (Zero for Non-Register Devices)

fi = Input Frequency

Ni = Number of Inputs at fi

All currents are in milliamps and all frequencies are in megahertz.

7. This test is performed with outputs tied to GND through a pull-down resistor.

			IDT74FCT621T		IDT74FCT621AT		
Symbol	Parameter	Condition ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
t PLH	Propagation Delay, A to B	CL = 50pF	5.5	13	5.5	12	ns
t PHL		$RL = 500\Omega$	1.5	8.5	1.5	6.8	
t PLH	Propagation Delay, B to A		5.5	12.5	5.5	12	ns
t PHL			1.5	8	1.5	6.4	
t PLH	Propagation Delay, GBA to A		5.5	14	5.5	13	ns
t PHL			1.5	8.5	1.5	6.8	
t PLH	Propagation Delay, GAB to B		5.5	14	5.5	13	ns
t PHL			1.5	8	1.5	6.4	

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

NOTES:

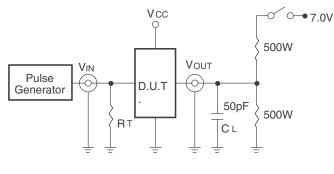
1. See test circuit and waveforms.

2. Minimum limits are guaranteed but not tested on Propagation Delays.

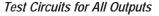
IDT74FCT621T/AT FASTCMOSOCTAL BUSTRANSCEIVER (OPEN DRAIN)

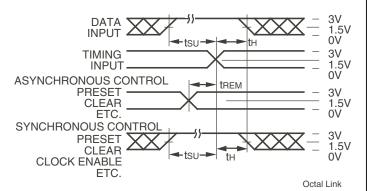
INDUSTRIAL TEMPERATURE RANGE

TEST CIRCUITS AND WAVEFORMS

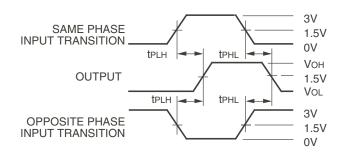


Octal Link









Propagation Delay

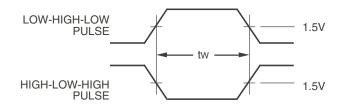
SWITCHPOSITION

Switch
Closed
Open

DEFINITIONS:

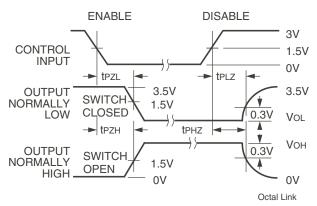
CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to Zout of the Pulse Generator.



Pulse Width

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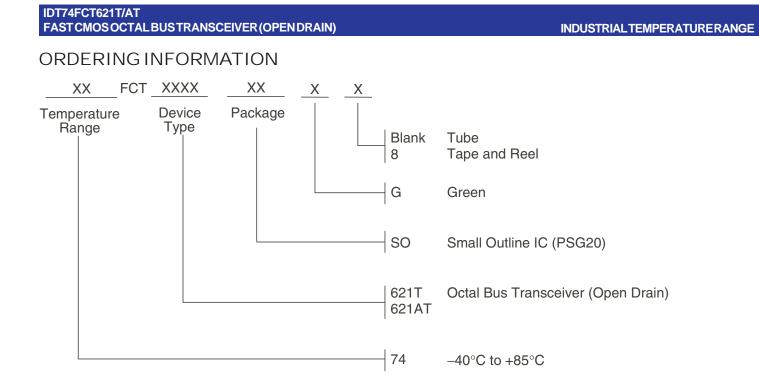


Enable and Disable Times

NOTES:

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tr \leq 2.5ns; tr \leq 2.5ns.

Octal Link



Datasheet Document History

10/10/2009 Pg. 6	Updated the orderin	g information by	y removing the	ie "IDT" notatio	n and non RoHS part.
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10/22/2014 Pg. 6 Added Tape & Reel to ordering information.

11/26/2016 Pg. 6 Updated ordering information diagram temperature symbol, removed tray and created Green option in greater detail.

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